

June 1999

LM195/LM395 Ultra Reliable Power Transistors

General Description

The LM195/LM395 are fast, monolithic power transistors with complete overload protection. These devices, which act as high gain power transistors, have included on the chip, current limiting, power limiting, and thermal overload protection making them virtually impossible to destroy from any type of overload. In the standard TO-3 transistor power package, the LM195 will deliver load currents in excess of 1.0A and can switch 40V in 500 ns.

The inclusion of thermal limiting, a feature not easily available in discrete designs, provides virtually absolute protection against overload. Excessive power dissipation or inadequate heat sinking causes the thermal limiting circuitry to turn off the device preventing excessive heating.

The LM195 offers a significant increase in reliability as well as simplifying power circuitry. In some applications, where protection is unusually difficult, such as switching regulators, lamp or solenoid drivers where normal power dissipation is low, the LM195 is especially advantageous.

The LM195 is easy to use and only a few precautions need be observed. Excessive collector to emitter voltage can destroy the LM195 as with any power transistor. When the device is used as an emitter follower with low source impedance, it is necessary to insert a 5.0k resistor in series with the base lead to prevent possible emitter follower oscillations. Although the device is usually stable as an emitter folower, the resistor eliminates the possibility of trouble without degrading performance. Finally, since it has good high frequency response, supply bypassing is recommended.

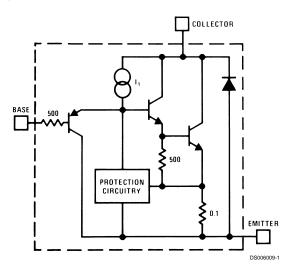
For low-power applications (under 100 mA), refer to the LP395 Ultra Reliable Power Transistor.

The LM195/LM395 are available in standard TO-3 power packages and solid Kovar TO-5. The LM195 is rated for operation from -55°C to +150°C and the LM395 from 0°C to +125°C.

Features

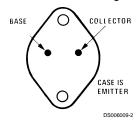
- Internal thermal limiting
- Greater than 1.0A output current
- 3.0 µA typical base current
- 500 ns switching time
- 2.0V saturation
- Base can be driven up to 40V without damage
- Directly interfaces with CMOS or TTL
- 100% electrical burn-in

Simplified Circuit



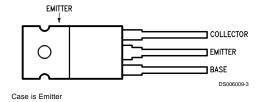
Connection Diagrams

TO-3 Metal Can Package



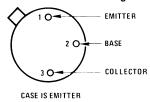
Bottom View Order Number LM195K/883 See NS Package Number K02A

TO-220 Plastic Package



Top View Order Number LM395T See NS Package Number T03B

TO-5 Metal Can Package



Bottom View Order Number LM195H/883 See NS Package Number H03B

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

| Collector to Emitter Voltage | |
|-----------------------------------|-----|
| LM195 | 42V |
| LM395 | 36V |
| Collector to Base Voltage | |
| LM195 | 42V |
| LM395 | 36V |
| Base to Emitter Voltage (Forward) | |
| LM195 | 42V |
| LM395 | 36V |

| Base to Emitter Voltage (Reverse) | 20V |
|-----------------------------------|--------------------|
| Collector Current | Internally Limited |
| Power Dissipation | Internally Limited |
| Operating Temperature Range | |
| LM195 | -55°C to +150°C |
| LM395 | 0°C to +125°C |
| Storage Temperature Range | -65°C to +150°C |
| Lead Temperature | |
| (Soldering, 10 sec.) | 260°C |
| | |

Preconditioning

100% Burn-In In Thermal Limit

Electrical Characteristics

(Note 2)

| Parameter | Conditions | LM195 | | | LM395 | | | Units | |
|-------------------------------------|--|-------|---------|---------|---------|-----|-----|-------|----|
| | | Min | Тур | Max | Min | Тур | Max | | |
| Collector-Emitter Operating Voltage | $I_Q \le I_C \le I_{MAX}$ | | | 42 | | | 36 | V | |
| (Note 4) | | | | | | | | | |
| Base to Emitter Breakdown Voltage | 0 ≤ V _{CE} ≤ V _{CEMAX} | 42 | | | 36 | 60 | | V | |
| Collector Current | | | | | | | | | |
| TO-3, TO-220 | V _{CE} ≤ 15V | 1.2 | 2.2 | | 1.0 | 2.2 | | Α | |
| TO-5 | V _{CE} ≤ 7.0V | 1.2 | 1.8 | | 1.0 | 1.8 | | Α | |
| Saturation Voltage | I _C ≤ 1.0A, T _A = 25°C | | 1.8 | 2.0 | | 1.8 | 2.2 | V | |
| Base Current | $0 \le I_C \le I_{MAX}$ | | 3.0 | 5.0 | 3.0 | 3.0 | 10 | μА | |
| | $0 \le V_{CE} \le V_{CEMAX}$ | | | | | 3.0 | | | |
| Quiescent Current (I _Q) | V _{be} = 0 | | 2.0 5.0 | 2.0 5.0 | 2.0 5.0 | 5.0 | 2.0 | 10 | mA |
| | $0 \le V_{CE} \le V_{CEMAX}$ | | | | | | 2.0 | | |
| Base to Emitter Voltage | $I_C = 1.0A, T_A = +25^{\circ}C$ | | 0.9 | | | 0.9 | | V | |
| Switching Time | $V_{CE} = 36V, R_{L} = 36\Omega,$ | | 500 | 0 | | 500 | | ns | |
| | $T_A = 25^{\circ}C$ | | | 300 | | | | | |
| Thermal Resistance Junction to | TO-3 Package (K) | | 2.3 | 3.0 | | 2.3 | 3.0 | °C/W | |
| Case (Note 3) | TO-5 Package (H) | | 12 | 15 | | 12 | 15 | °C/W | |
| | TO-220 Package (T) | | | | | 4 | 6 | °C/W | |

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Note 2: Unless otherwise specified, these specifications apply for $-55^{\circ}\text{C} \le T_{j} \le +150^{\circ}\text{C}$ for the LM195 and $0^{\circ}\text{C} \le +125^{\circ}\text{C}$ for the LM395.

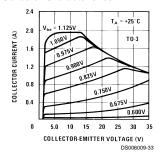
Note 3: Without a heat sink, the thermal resistance of the TO-5 package is about +150°C/W, while that of the TO-3 package is +35°C/W.

Note 4: Selected devices with higher breakdown available.

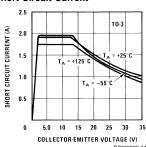
Note 5: Refer to RETS195H and RETS195K drawings of military LM195H and LM195K versions for specifications.

Typical Performance Characteristics (for K and T Packages)

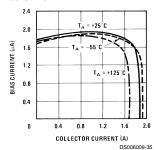
Collector Characteristics



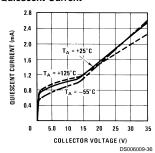
Short Circuit Current



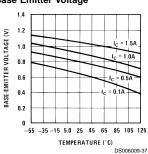
Bias Current



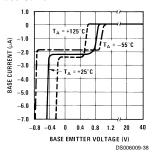
Quiescent Current



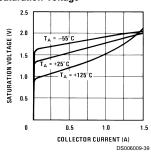
Base Emitter Voltage



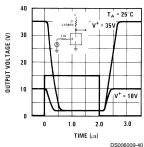
Base Current



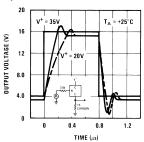
Saturation Voltage



Response Time

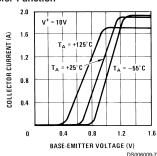


Response Time

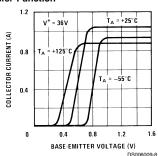


Typical Performance Characteristics (for K and T Packages) (Continued)

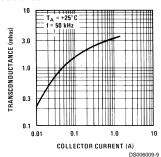
10V Transfer Function



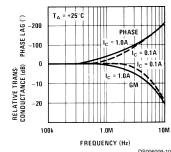
36V Transfer Function

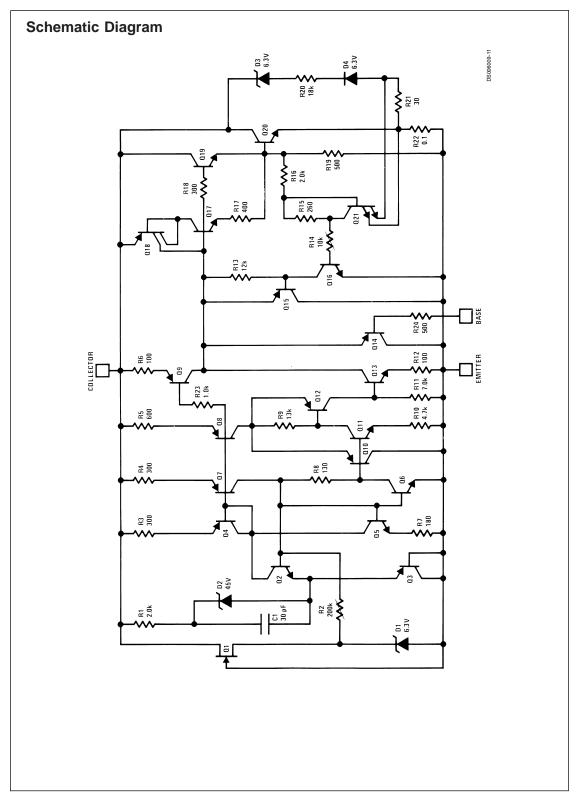


Transconductance



Small Signal Frequency Response

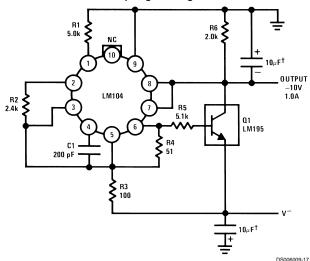




Typical Applications 1.0 Amp Voltage Follower DS006009-12 *Solid Tantalum Power PNP Time Delay COLLECTOR *Protects against excessive base drive **Needed for stability DS006009-14 1.0 MHz Oscillator 1.0 Amp Lamp Flasher 01 2N2222 DS006009-15

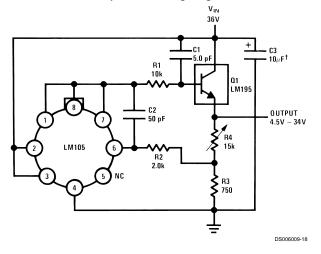
Typical Applications (Continued)

1.0 Amp Negative Regulator



†Solid Tantalum

1.0 Amp Positive Voltage Regulator

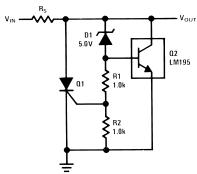


†Solid Tantalum

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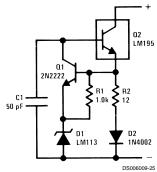
Typical Applications (Continued) Fast Optically Isolated Switch **Optically Isolated Power Transistor** OUTPUT Q1 LM195 DS006009-20 40V Switch **CMOS** or TTL Lamp Interface **Two Terminal Current Limiter** *Drive Voltage 0V to $\ge 10V \le 42V$

6.0V Shunt Regulator with Crowbar



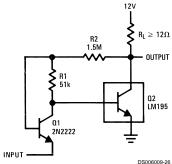
Two Terminal 100 mA Current Regulator

OUTPUT



Typical Applications (Continued)

Low Level Power Switch



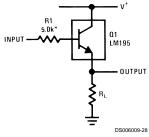
Turn ON = 350 mV Turn OFF = 200 mV

$\begin{array}{c} V^{+} \\ 12V \\ \\ 1N914 \\ \\ R1 \\ 12k \\ \\ 0.22_{\mu}F \\ \\ 0.22_{\mu}F \\ \\ 0.22_{\mu}F \\ \\ 0.33k \\ \\ R_{L} \geq 12\Omega \\ \end{array}$

Power One-Shot

T = R1C R2 = 3R1 $R2 \le 82k$

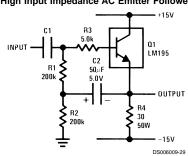
Emitter Follower

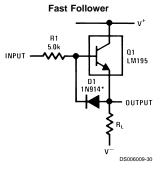


*Need for Stability

High Input Impedance AC Emitter Follower

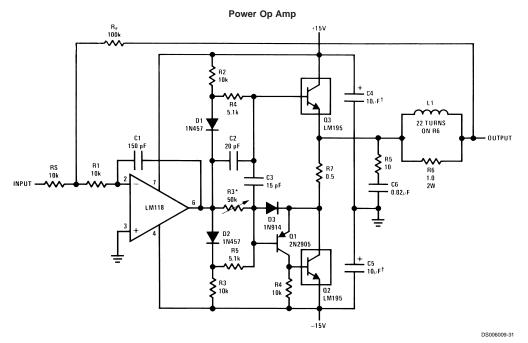
DS006009-27





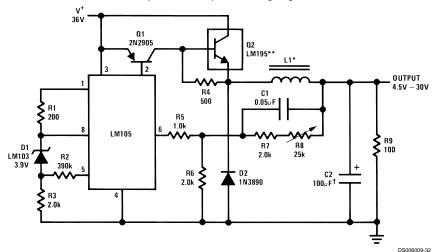
*Prevents storage with fast fall time square wave drive

Typical Applications (Continued)

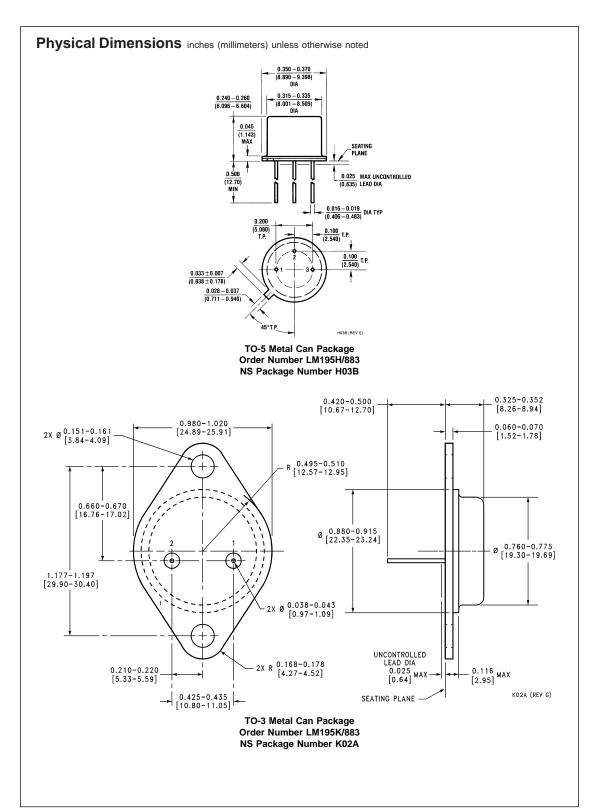


*Adjust for 50 mA quiescent current †Solid Tantalum

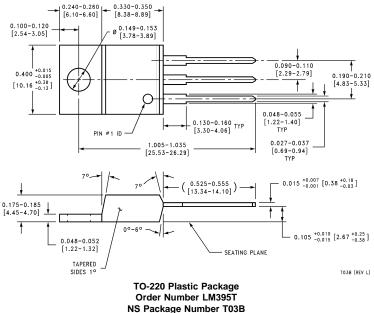
6.0 Amp Variable Output Switching Regulator



- *Sixty turns wound on Arnold Type A-083081-2 core.
- **Four devices in parallel
- †Solid tantalum



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



NS Package Number T03E

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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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